

**450V NPN HIGH VOLTAGE POWER TRANSISTOR**

**Features**

- $BV_{CEO} > 450V$
- $BV_{CES} > 700V$
- $BV_{EBO} > 9V$
- $I_C = 4A$  High Collector Current
- Integrated Anti-Parallel Diode to act as Free-Wheeling Diode
- Anti-Saturation Feature
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please [contact us](https://www.diodes.com/quality/product-definitions/) or your local Diodes representative. <https://www.diodes.com/quality/product-definitions/>**

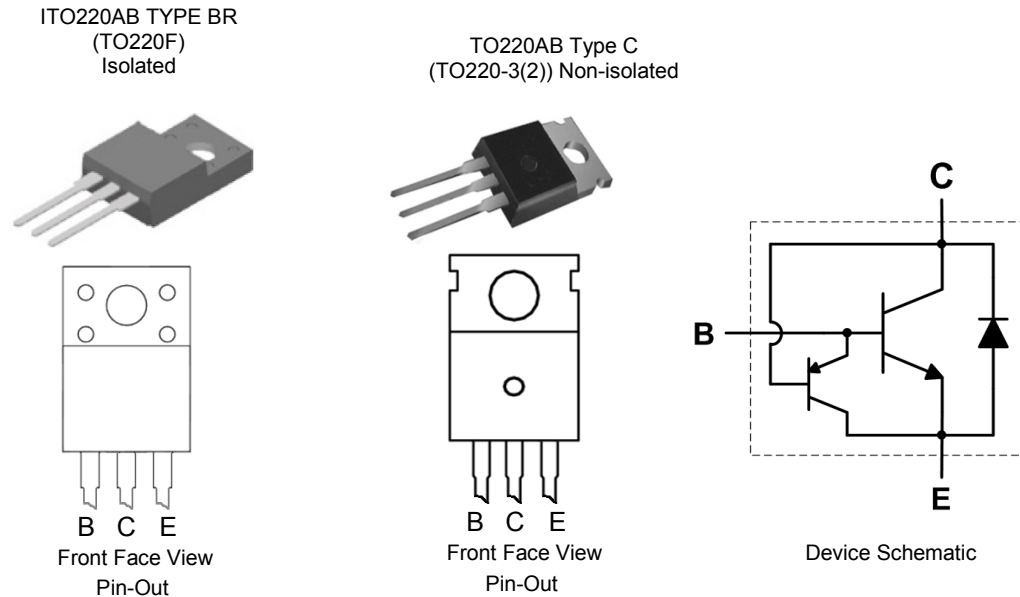
**Mechanical Data**

- Case: ITO220AB TYPE BR (TO220F), TO220AB Type C
- Case Material: Molded Plastic, "Green" Molding Compound  
UL Flammability Classification Rating 94V-0
- Terminals: Finish - Matte Tin Finish Leads, Solderable per MIL-STD-202, Method 208 (E3)
- Weight: ITO220AB TYPE BR (TO220F): 1500mg (Approximate)  
TO220AB Type C : 2000mg (Approximate)

**Applications**

Low power AC-DC SMPS for:

- Battery Chargers for Mobile Phone / Tablets / Smartphones
- Power Supply for DVD / STB
- LED Lighting



**Ordering Information** (Note 4)

Product	Package	Marking	Quantity
APT13005DTF-G1	ITO220AB TYPE BR (TO220F)	APT13005DTF-G1	1000 per Box in Tubes
APT13005DT-G1	TO220AB Type C (TO220-3(2))	APT13005DT-G1	1000 per Box in Tubes

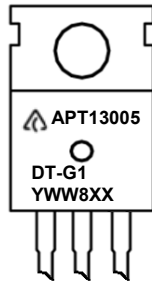
- Notes:
1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
  2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
  3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
  4. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>.

## Marking Information

ITO220AB TYPE



TO220AB Type C



= Manufacturers' code marking  
 For ITO220AB TYPE BR (TO220F), APT13005DTF-G1 = Product Type Marking ID  
 For TO220AB Type C, APT13005DT-G1 = Product Type Marking ID  
 YWW = Date Code Marking  
     e.g. 312 = Year 2013, Week 12.  
 8 = Assembly site code  
 XX = Batch Number

## Absolute Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Emitter Voltage	V <sub>CES</sub>	700	V
Collector-Emitter Voltage	V <sub>CEO</sub>	450	V
Emitter-Base Voltage	V <sub>EBO</sub>	9	V
Collector Current	I <sub>C</sub>	4	A
Peak Collector Current	I <sub>CM</sub>	8	A
Base Current	I <sub>B</sub>	2	A
Peak Base Current	I <sub>BM</sub>	4	A

## Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation @T <sub>C</sub> = +25°C	P <sub>D</sub>	For ITO220AB TYPE BR (TO220F)	28
		For TO220AB Type C	75
Thermal Resistance, Junction to Case	R <sub>θJC</sub>	For ITO220AB TYPE BR (TO220F)	4.5
		For TO220AB Type C	1.67
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-65 to +150	°C

## ESD Ratings (Note 5)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	8,000	V	3B
Electrostatic Discharge - Machine Model	ESD MM	400	V	C

Note: 5. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

**Safe Operating Areas** (@ $T_A = +25^\circ\text{C}$ , unless otherwise specified.)

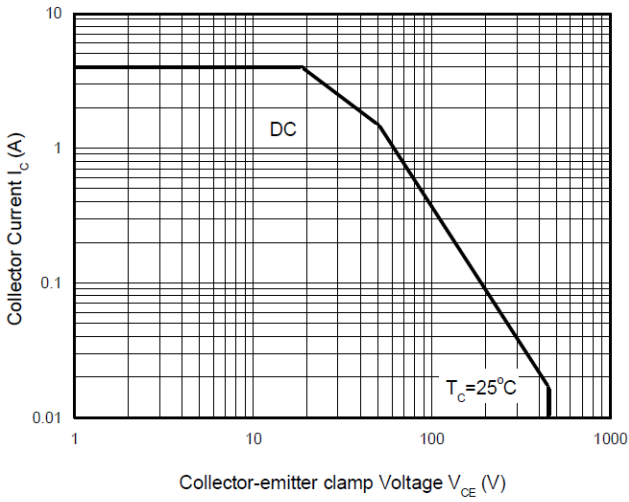


Figure 4. Safe Operating Areas  
TO220AB Type C

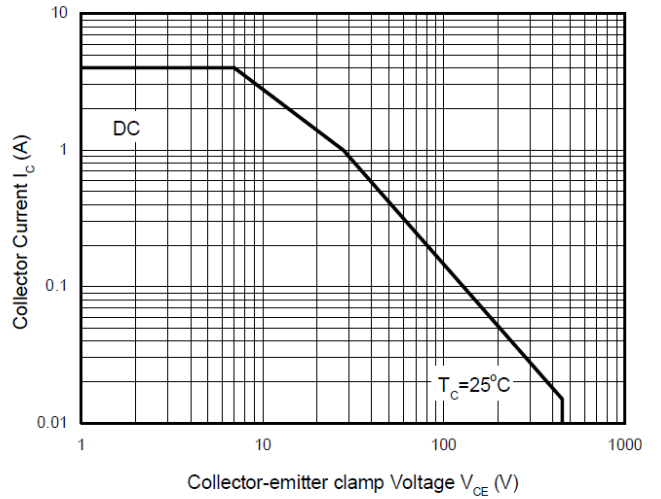


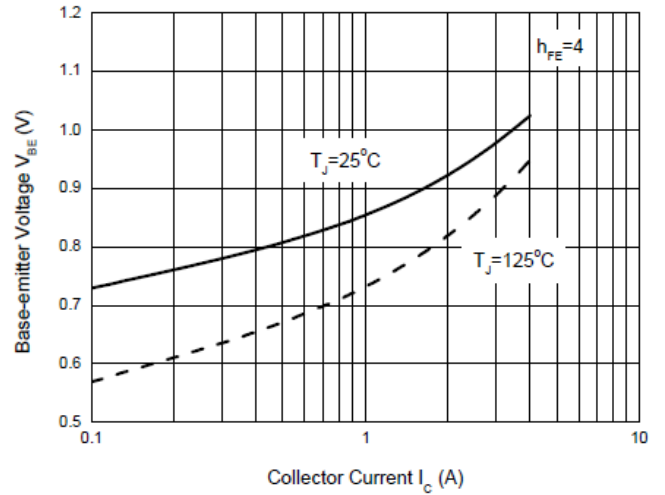
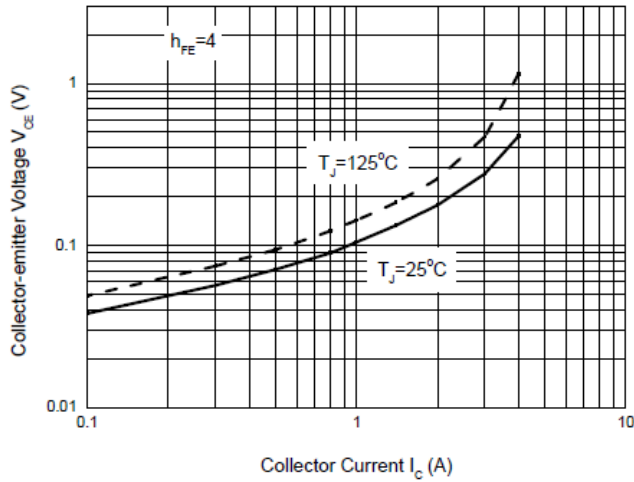
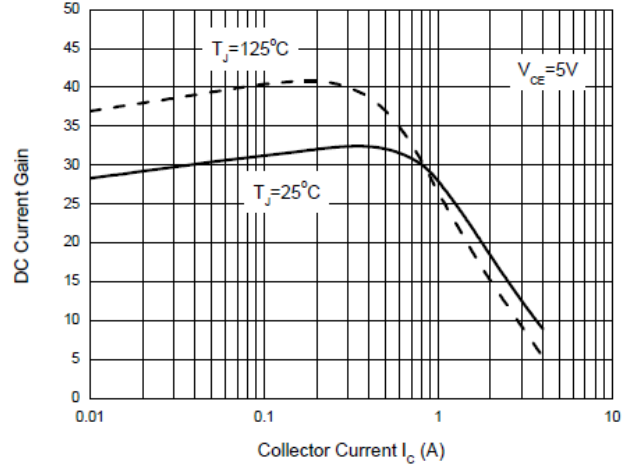
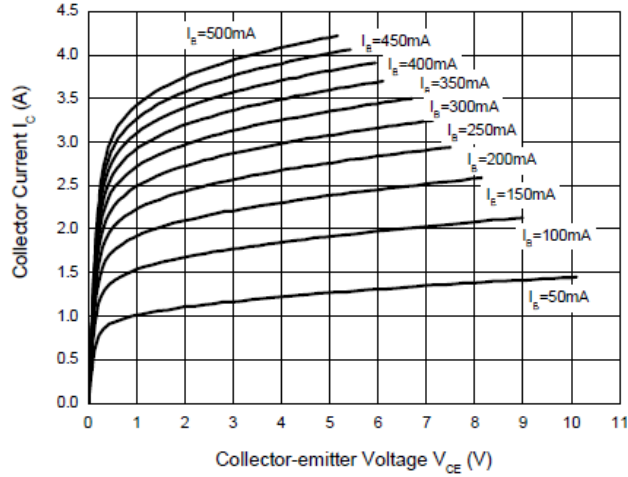
Figure 5. Safe Operating Areas  
ITO220AB Type BR (TO220F)

**Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Emitter Breakdown Voltage	BV <sub>CES</sub>	700	—	—	V	I <sub>C</sub> = 100μA, V <sub>BE</sub> = 0V
Collector-Emitter Breakdown Voltage	BV <sub>CEO</sub>	450	—	—	V	I <sub>C</sub> = 100μA
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	9	—	—	V	I <sub>E</sub> = 100μA
Collector Cutoff Current	I <sub>CEV</sub>	—	—	10	μA	V <sub>CE</sub> = 700V, V <sub>BE</sub> = -1.5V
DC current transfer Static ratio (Note 6)	h <sub>FE</sub>	15 8	—	35 35	— —	I <sub>C</sub> = 1A, V <sub>CE</sub> = 5V I <sub>C</sub> = 2A, V <sub>CE</sub> = 5V
Collector-Emitter Saturation Voltage (Note 6)	V <sub>CE(sat)</sub>	— — —	— — —	0.3 0.6 0.9	V	I <sub>C</sub> = 1A, I <sub>B</sub> = 0.2A I <sub>C</sub> = 2A, I <sub>B</sub> = 0.5A I <sub>C</sub> = 4A, I <sub>B</sub> = 1A
Base-Emitter Saturation Voltage (Note 6)	V <sub>BE(sat)</sub>	— —	— —	1.1 1.3	V	I <sub>C</sub> = 1A, I <sub>B</sub> = 0.2A I <sub>C</sub> = 2A, I <sub>B</sub> = 0.5A
Output Capacitance	C <sub>obo</sub>	—	45	—	pF	V <sub>CB</sub> = 10V, f = 0.1MHz
Transition Frequency	f <sub>T</sub>	4	—	—	MHz	I <sub>C</sub> = 0.5A, V <sub>CE</sub> = 10V
Turn-on Time with Resistive Load	t <sub>on</sub>	—	—	0.7	μs	I <sub>C</sub> = 2A, V <sub>CC</sub> = 125V I <sub>B1</sub> = -I <sub>B2</sub> = 0.4A
Storage Time with Resistive Load	t <sub>s</sub>	—	—	4.0		
Fall Time with Resistive Load	t <sub>f</sub>	—	—	0.8		

Note: 6. Measured under pulsed conditions. Pulse width ≤ 300μs. Duty cycle ≤ 2%.

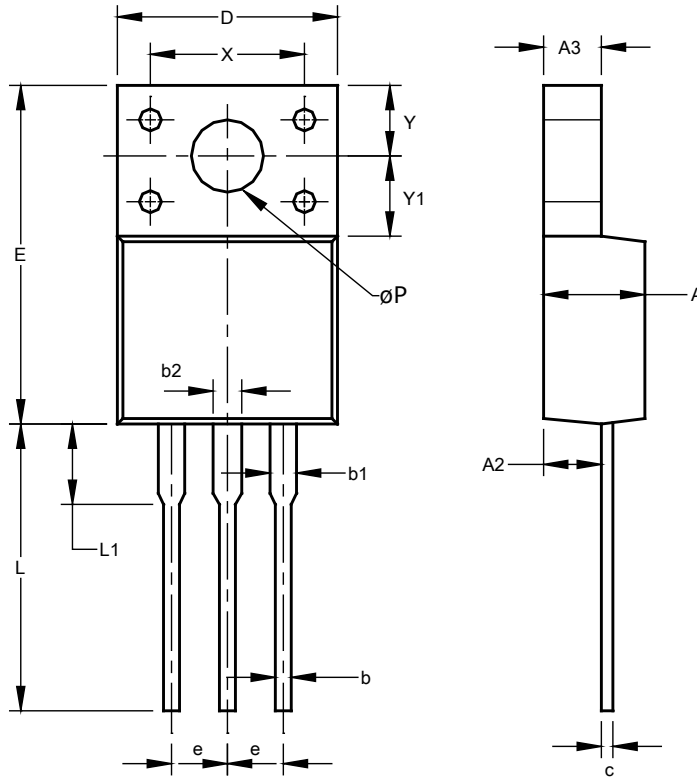
**Typical Electrical Characteristics** (@ $T_A = +25^\circ\text{C}$ , unless otherwise specified.)



**Package Outline Dimensions**

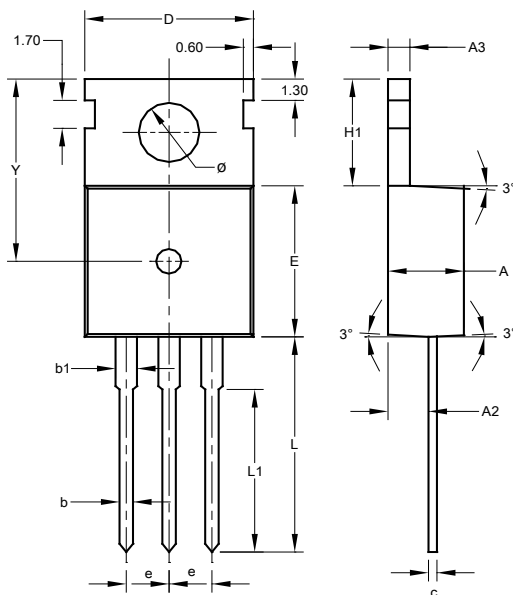
Please see <http://www.diodes.com/package-outlines.html> for the latest version.

**ITO220AB Type BR (TO220F)**



ITO220AB Type BR (TO220F)			
Dim	Min	Max	Typ
A	4.300	4.900	-
A2	2.520	2.920	-
A3	2.350	2.900	-
b	0.550	0.900	-
b1	1.000	1.400	-
b2	1.100	1.500	-
c	0.450	0.600	-
D	9.70	10.30	-
E	14.70	16.00	-
e	-	-	2.54
L	12.50	13.50	-
L1	2.790	4.500	-
X	6.90	7.10	-
Y	3.000	3.400	-
Y1	3.370	3.900	-
$\phi P$	3.000	3.550	-
All Dimensions in mm			

**TO220AB Type C**



TO220AB Type C			
Dim	Min	Max	Typ
A	-	-	4.500
A2	-	-	2.400
A3	-	-	1.300
b	0.700	0.900	-
b1	-	-	1.270
c	0.400	0.600	-
D	9.800	10.200	-
E	9.000	9.400	-
e	-	-	2.54
H1	6.300	6.700	-
L	12.600	13.600	-
L1	9.600	10.600	-
Y	-	-	11.100
$\phi$	3.560	3.640	-
All Dimensions in mm			

Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device Terminals and PCB tracking.

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